

**FEATURES**

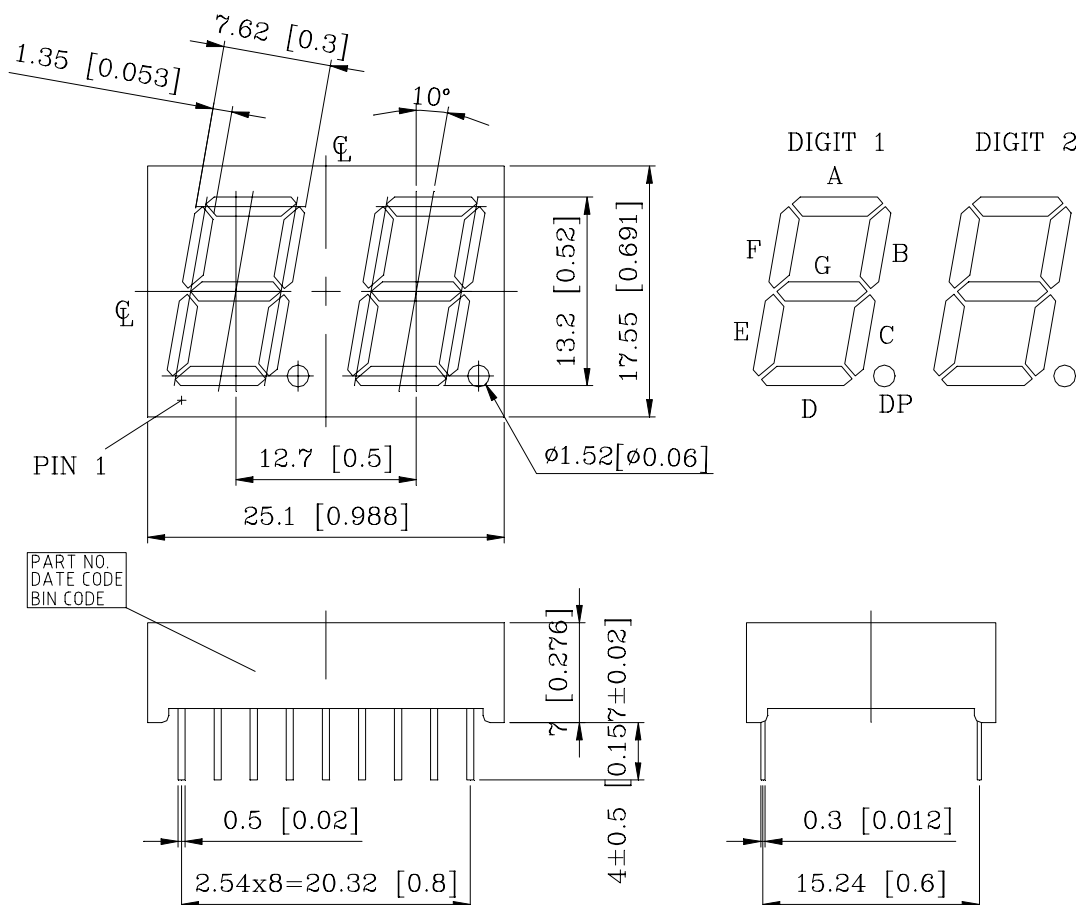
- \* 0.52 inch (13.2 mm) DIGIT HEIGHT
- \* CONTINUOUS UNIFORM SEGMENTS
- \* LOW POWER REQUIREMENT
- \* EXCELLENT CHARACTERS APPEARANCE
- \* HIGH BRIGHTNESS & HIGH CONTRAST
- \* WIDE VIEWING ANGLE
- \* SOLID STATE RELIABILITY
- \* CATEGORIZED FOR LUMINOUS INTENSITY

**DESCRIPTION**

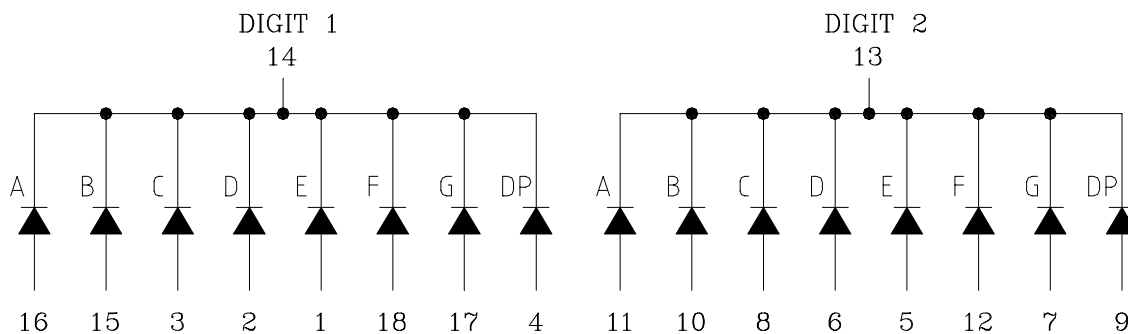
The LTD-5260HR is a 0.52 inch (13.2 mm) digit height dual digit seven-segment display. The device utilizes high efficiency red LED chips, which are made from GaAsP on a transparent GaP substrate, and has a red face and red segments.

**DEVICE**

PART NO	DESCRIPTION
Hi-Eff. Red	COMMON CATHODE RT. HAND DECIMAL
LTD-5260HR	

**PACKAGE DIMENSIONS**


NOTES: All dimensions are in millimeters. Tolerances are  $\pm 0.25$  mm unless otherwise noted.

**INTERNAL CIRCUIT DIAGRAM**


**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	ANODE E (DIGIT 1)
2	ANODE D (DIGIT 1)
3	ANODE C (DIGIT 1)
4	ANODE DP (DIGIT 1)
5	ANODE E (DIGIT 2)
6	ANODE D (DIGIT 2)
7	ANODE G (DIGIT 2)
8	ANODE C (DIGIT 2)
9	ANODE DP (DIGIT 2)
10	ANODE B (DIGIT 2)
11	ANODE A (DIGIT 2)
12	ANODE F (DIGIT 2)
13	COMMON CATHODE (DIGIT 2)
14	COMMON CATHODE (DIGIT 1)
15	ANODE B (DIGIT 1)
16	ANODE A (DIGIT 1)
17	ANODE G (DIGIT 1)
18	ANODE F (DIGIT 1)

**ABSOLUTE MAXIMUM RATING AT T<sub>A</sub>=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Chip	75	mW
Peak Forward Current Per Chip ( 1/10 Duty Cycle, 0.1ms Pulse Width )	100	mA
Continuous Forward Current Per Chip	25	mA
Derating Linear From 25°C Per Chip	0.33	mA/°C
Reverse Voltage Per Chip	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane		

**TRICAL / OPTICAL CHARACTERISTICS AT T<sub>A</sub>=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	800	2200		μcd	I <sub>F</sub> =10mA
Peak Emission Wavelength	λ <sub>p</sub>		635		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		40		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		623		nm	I <sub>F</sub> =20mA
Forward Voltage Per Chip	V <sub>F</sub>		2	2.6	V	I <sub>F</sub> =20mA
Reverse Current Per Chip	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

**TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES**

(25°C Ambient Temperature Unless Otherwise Noted)

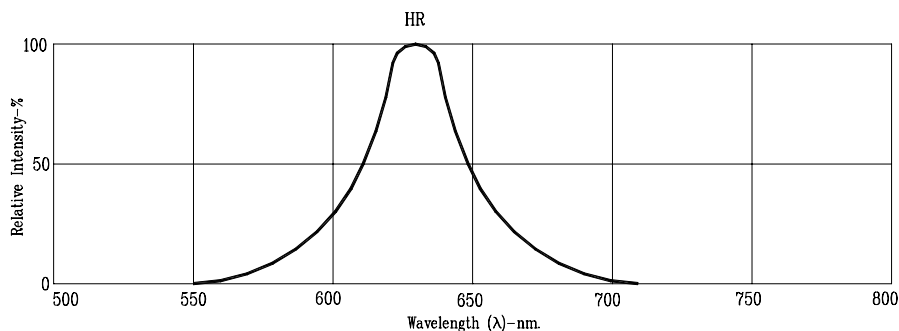


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

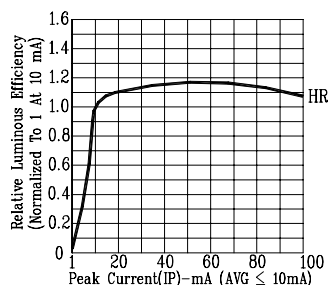


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

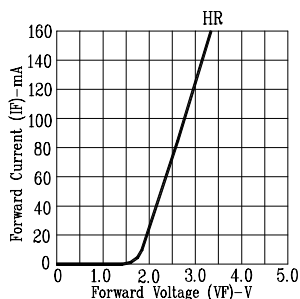


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

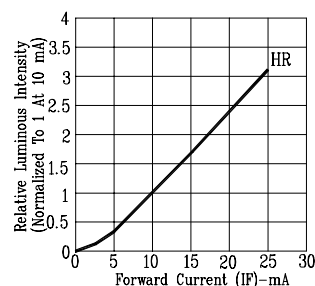


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

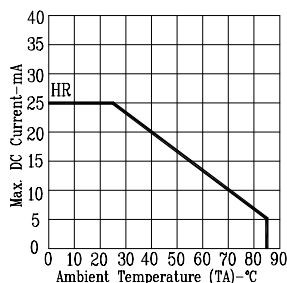


Fig5. MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

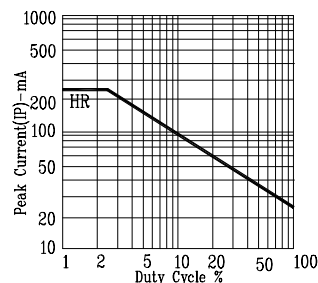


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: HR=HL - EFF. RED